# 2SB0934 (2SB934)

# Silicon PNP epitaxial planar type

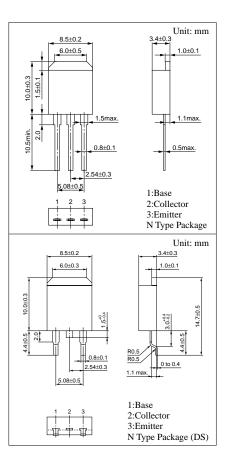
For power switching Complementary to 2SD1257

#### Features

- Low collector to emitter saturation voltage V<sub>CE(sat)</sub>
- Satisfactory linearity of foward current transfer ratio h<sub>FE</sub>
- Large collector current I<sub>C</sub>
- N type package enabling direct soldering of the radiating fin to the printed circuit board, etc. of small electronic equipment.

## Absolute Maximum Ratings $(T_C=25^{\circ}C)$

Parameter		Symbol	Ratings	Unit	
Collector to base voltage		$V_{CBO}$	-130	V	
Collector to emitter voltage		$V_{CEO}$	-80	V	
Emitter to base voltage		$V_{\mathrm{EBO}}$	-7	V	
Peak collector current		I <sub>CP</sub>	-15	A	
Collector current		$I_{C}$	-7	A	
Collector power	T <sub>C</sub> =25°C	D	40	***	
dissipation	Ta=25°C	$P_{C}$	1.3	W	
Junction temperature		T <sub>j</sub>	150	°C	
Storage temperature		$T_{\rm stg}$	-55 to +150	°C	



# ■ Electrical Characteristics (T<sub>C</sub>=25°C)

Parameter	Symbol	Conditions	min	typ	max	Unit
Collector cutoff current	$I_{CBO}$	$V_{CB} = -100V, I_E = 0$			-10	μА
Emitter cutoff current	$I_{EBO}$	$V_{EB} = -5V, I_C = 0$			-50	μΑ
Collector to emitter voltage	V <sub>CEO</sub>	$I_{C} = -10\text{mA}, I_{B} = 0$	-80			V
Forward current transfer ratio	h <sub>FE1</sub>	$V_{CE} = -2V, I_C = -0.1A$	45			
	h <sub>FE2</sub> *	$V_{CE} = -2V, I_C = -3A$	90		260	
Collector to emitter saturation voltage	V <sub>CE(sat)</sub>	$I_C = -5A, I_B = -0.25A$			- 0.5	V
Base to emitter saturation voltage	V <sub>BE(sat)</sub>	$I_C = -5A, I_B = -0.25A$			-1.5	V
Transition frequency	$f_T$	$V_{CE} = -10V, I_{C} = -0.5A, f = 10MHz$		30		MHz
Turn-on time	t <sub>on</sub>			0.5		μs
Storage time	t <sub>stg</sub>	$I_C = -3A$ , $I_{B1} = -0.3A$ , $I_{B2} = 0.3A$		1.5		μs
Fall time	$t_{\mathrm{f}}$			0.1		μs

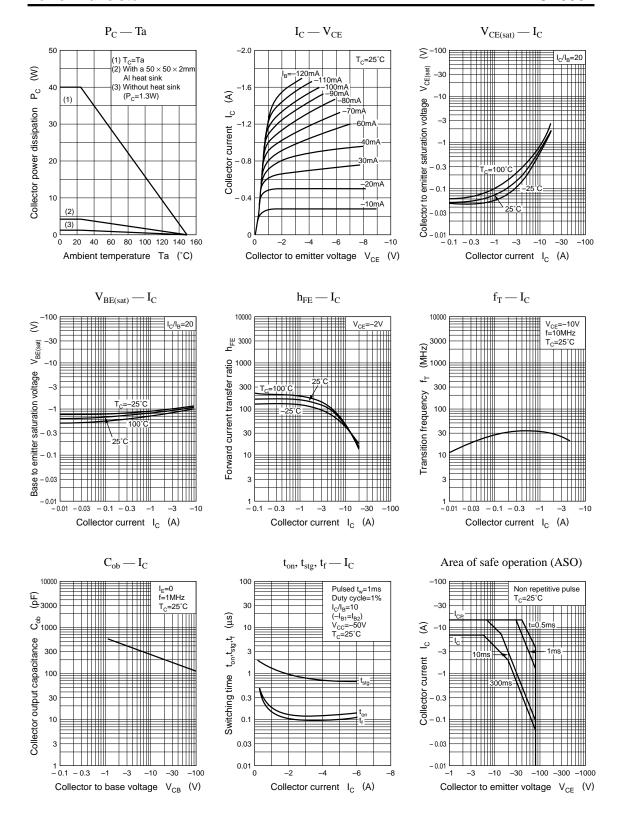
#### \*h<sub>FE2</sub> Rank classification

Rank	Q	P		
h <sub>FE2</sub>	90 to 180	130 to 260		

Note) The part number in the parenthesis shows conventional part number.

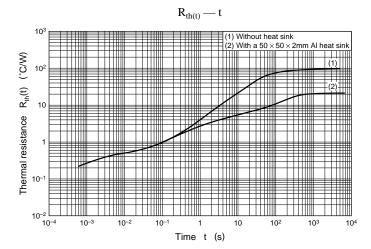
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